

isc Silicon NPN Power Transistor

KSH31C

DESCRIPTION

- Lead formed for surface mount applications(NO suffix)
- Straight lead(IPAK, "-I" suffix)
- Electrically similar to popular TIP31C
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

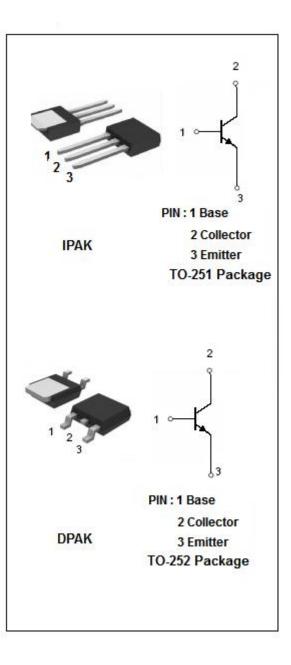
Tstg

· General purpose amplifier low speed switching application

ABSOLUTE MAXIMUM RATINGS(Ta=25°C) SYMBOL PARAMETER VALUE UNIT 100 V V_{сво} Collector-Base Voltage Collector-Emitter Voltage 100 V V_{CEO} VEBO Emitter-Base Voltage 5 V Collector Current-Continuous lc 3 А Total Power Dissipation Pc 1.56 W @ Ta=25℃ **Total Power Dissipation** Pc 15 W @ Tc=25℃ ΤJ Junction Temperature 150 °C

-55~150

°C



Storage Temperature Range



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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
V(BR)CEO *	Collector-Emitter Breakdown Voltage	Ic= 30mA; I _B = 0	100			V
V _{CE(sat)*}	Collector-Emitter Saturation Voltage	I _C = 3A; I _B = 375mA			1.2	V
V _{BE} (on)*	Base-Emitter On Voltage	I _C = 3A; V _{CE} =4V			1.8	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 100V; I _E = 0			20	uA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			1.0	mA
h _{FE1*}	DC Current Gain	I _C = 1A; V _{CE} = 4V	25			
h _{FE2*}	DC Current Gain	I _C = 3A; V _{CE} = 4V	10		50	
f⊤	Current-Gain—Bandwidth Product	I _C = 0.5A; V _{CE} = 10V	3			MHz

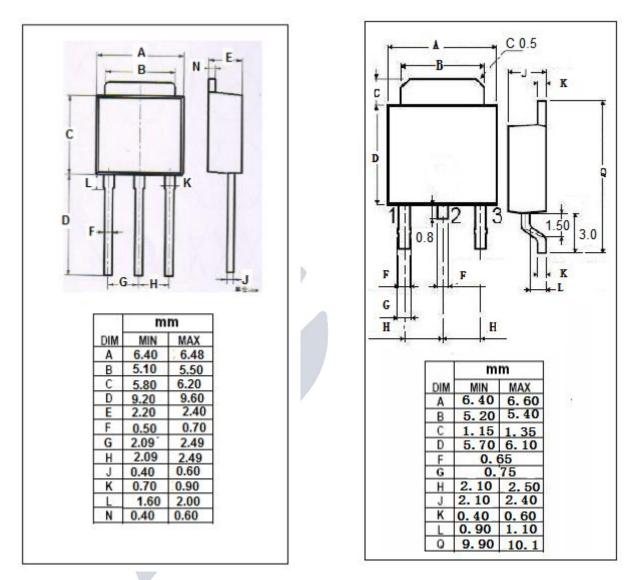
*:Pulse test PW≤300us,duty cycle≤2%



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Outline Drawing



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